

400nA ultra low I_Q, 1.0MHz, 500mA Synchronous Step Down Regulator

General Description

The SY20109 is a 400nÅ ultra low quiescent current, 1.0MHz synchronous step down DC/DC regulator capable of delivering up to 500mÅ output current. It can operate over a wide input voltage range from 2.2V to 6.5V and integrates main switch and synchronous switch with very low $R_{DS(ON)}$ to minimize the conduction loss.

The low output voltage ripple, the small external inductor and the capacitor sizes are achieved at 1.0MHz switching frequency.

Ordering Information

Typical Applications

SY20109 □(□□)□

Temperature Code
Package Code
 Optional Spec Code

Ordering Number	Package type	Note
SY20109DFC	DFN2×2-8	

Features

- 2.2~6.5V Input Voltage Range
- Ultra Low Quiescent Current Down to 400nA
- Low $R_{DS(ON)}$ for Internal Switches (Top/Bottom) $300m\Omega/130m\Omega$
- Instant PWM Control to Achieve Ultra Fast Load Transient Speed
- High Switching Frequency 1.0MHz Minimizes the External Components
- Internal Soft-start Limits the Inrush Current
- Power Good Indicator
- Hiccup Mode for Output Short Circuit Protection
- 100% Drop Out Operation
- Output Auto Discharge Function
- RoHS Compliant and Halogen Free
- Compact Package: DFN2×2-8

Applications

- Battery Powered Applications
- Consumer and Portable Medical Products
- Personal Ware Products

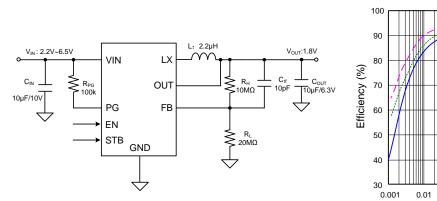


Figure1. Schematic Diagram

Efficiency vs. Output Current

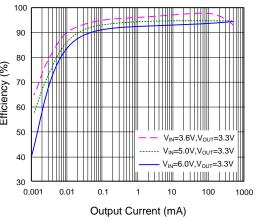
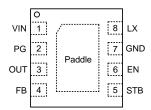


Figure2. Efficiency vs. Output Current



Pinout (Top View)



(DFN2×2-8)

Pin Name	Pin Number	Pin Description				
VIN	1	Power input pin. Decouple this pin to the GND pin with at least a 10μ F ceramic capacitor.				
PG	2	Power good indicator (open-drain output). Low if the output < 90% of the regulation; high otherwise. Connecting a pull-up resistor to the input.				
OUT	3	Output voltage feedback pin. Connecting this pin to the output side.				
FB	4	Connecting this pin to the center point of the output resistor divider (as shown in Figure 1) to program the output voltage: $V_{OUT}=1.2V\times(1+R_H/R_L)$.				
STB	5	This pin controls the standby mode. With STB = low, deep standby function will be activated, $I_Q=400$ nA. With STB = high, deep standby function will be disabled, $I_Q=15\mu$ A.				
EN	6	Enable control. Pulled high to turn on. Do not leave it floating.				
GND	7	Power ground pin.				
LX	8	Inductor pin. Connect this pin to the switching node of the inductor.				

Absolute Maximum Ratings (Note 1)

Supply Input Voltage	0.3V to 7V
PG, OUT, STB, EN	$-0.3V$ to VIN + 0.6V
LX Voltage	0.3V $^{(*1)}$ to 7V $^{(*2)}$
Power Dissipation, PD @ $T_A = 25^{\circ}C$,	
DFN2×2-8	1.1W
Package Thermal Resistance (Note 2)	
heta JA	85°C /W
θ _{JC}	45°C /W
Junction Temperature Range	40°C to 150°C
Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range ^(*1) LX Voltage Tested Down to -3V<20ns ^(*2) LX Voltage Tested Up to +7.5V<20ns	65°C to 150°C

Recommended Operating Conditions (Note 3)

Supply Input Voltage	2.2V to 6.5V
Junction Temperature Range	-40°C to 125°C
Ambient Temperature Range	-40°C to 85°C



Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Input Voltage Range	V _{IN}		2.2		6.5	V
Input UVLO Threshold	V _{UVLO}				2.2	V
Input UVLO Hysteresis	V _{HYS}			0.35		V
Ouissesset Comment	T	$V_{FB}=V_{REF}\times 115\%$, STB=0		400	600	nA
Quiescent Current	IQ	$V_{FB}=V_{REF}\times 115\%$, STB=1		15		μA
Shutdown Current	I _{SHDN}	V _{EN} =0V		10	100	nA
Feedback Reference Voltage	V _{REF}		1.182	1.2	1.218	V
LX Node Discharge Resistance	R _{DIS}			10		Ω
Top FET R _{ON}	R _{DS(ON)1}			300		mΩ
Bottom FET R _{ON}	R _{DS(ON)2}			130		mΩ
EN Input Voltage High	$V_{\rm EN,H}$		1.1			V
EN Input Voltage Low	$V_{\text{EN,L}}$				0.4	V
Power Good Threshold	V _{PG}	V _{FB} rising (good)		90		$%V_{REF}$
Power Good Delay	t _{PG,F}	High to low		20		μs
Min ON Time	t _{ON,MIN}			80		ns
Maximum Duty Cycle	D _{MAX}		100			%
Turn-on Delay	t _{ON,DLY}	from EN high to LX start switching		600		μs
Switching Frequency	f _{SW}	V _{OUT} =1.2V, I _{OUT} =500mA		1		MHz
Top FET Current Limit	I _{LMT,TOP}		0.9		1.5	А
Bottom FET Current Limit	I _{LMT,BOT}		0.5			А
Output Under Voltage Protection Threshold	V _{UVP.OUT}	V _{OUT} threshold		1		V
Output UVP Delay	t _{UVP,DLY}			20		μs
UVP Hiccup ON Time	t _{UVP,ON}			0.25		ms
UVP Hiccup OFF Time	t _{UVP,OFF}			0.25		ms
Thermal Shutdown Temperature	T _{SD}			150		°C
Thermal Shutdown Hysteresis	T _{HYS}			15		°C

 $(V_{IN} = 5.0V, V_{OUT} = 1.8V, L = 2.2\mu H, C_{OUT} = 10\mu F, T_A = 25^{\circ}C$, unless otherwise specified)

Note 1: Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

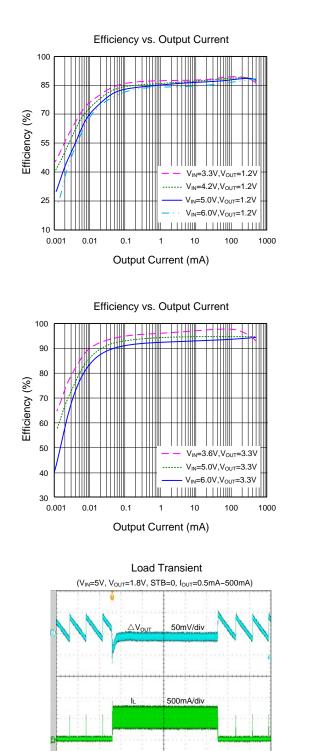
Note 2: θ_{JA} of SY20109DFC is measured in the natural convection at $T_A = 25^{\circ}C$ on 2OZ two-layer Silergy evaluation board. Paddle of DFN2×2-8 package is the case position for SY20109DFC θ_{JC} measurement.

Note 3: The device is not guaranteed to function outside its operating conditions.

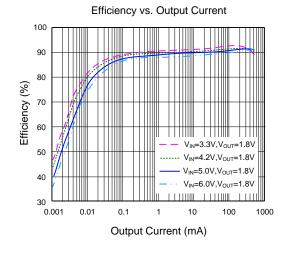


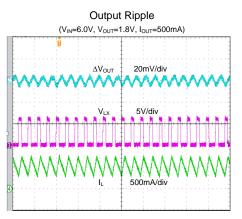
Typical Performance Characteristics

SILERGY

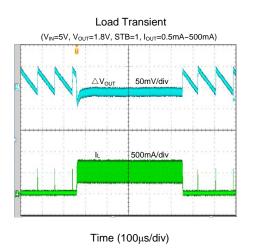


Time (100µs/div)



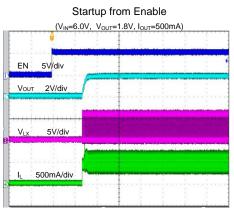


Time (2µs/div)

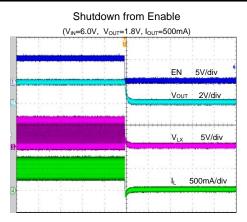




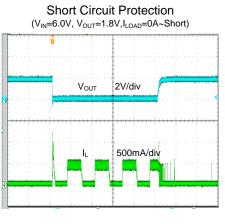
SY20109



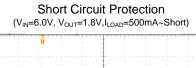
Time (400µs/div)

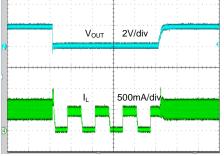


Time (400µs/div)



Time (400µs/div)





Time (400µs/div)



Operation

The SY20109 is a high efficiency, 1.0MHz synchronous step down DC/DC regulator capable of delivering up to 500mA output current. It can operate over a wide input voltage range from 2.2V to 6.5V and integrates main switch and synchronous switch with very low $R_{DS\ (ON)}$ to minimize the conduction loss.

Low output voltage ripple, small external inductor and capacitor sizes are achieved at 1.0MHz switching frequency.

Applications Information

Because of the high integration in the SY20109, the application circuit based on this regulator is rather simple. Only the input capacitor C_{IN} , the output capacitor C_{OUT} , the output inductor L, the feedback resistors (R_H and R_L) and the feed-forward capacitor C_{ff} need to be selected for the targeted application specifications.

Feedback Resistor Dividers RH and RL

Choose R_H and R_L to program the proper output voltage. To minimize the power consumption under light loads, it is desirable to choose large resistance values for both R_H and R_L . A value of between 10M Ω and 50M Ω is highly recommended for both resistors. If $R_L = 20M\Omega$ is chosen, then R_H can be calculated to be:

$$R_{\rm H} = \frac{(V_{\rm OUT} - 1.2 \, \rm V) \cdot R_{\rm L}}{1.2 \, \rm V}$$

Feed-forward Capacitor Cff

The feed-forward capacitor is needed to achieve good stability and fast dynamic response. At least a 10pF ceramic capacitor is recommended for the application.

Input Capacitor CIN

A typical X5R or a better grade ceramic capacitor with 10V rating and greater than 10μ F capacitance is recommended. Place this ceramic capacitor really close to the IN and GND pins to minimize the potential noise problem. Care should be taken to minimize the loop area formed by C_{IN}, and IN/GND pins.

Output Inductor L

There are several considerations in choosing this inductor.

1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple

current to be about 40% of the maximum output current. The inductance is calculated as:

$$L = \frac{V_{\text{OUT}}(1 - V_{\text{OUT}}/V_{\text{IN,MAX}})}{f_{\text{SW}} \times I_{\text{OUT,MAX}} \times 40\%}$$

Where f_{SW} is the switching frequency and $I_{OUT,MAX}$ is the maximum load current.

2) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

 $I_{\text{SAT, MIN}} > I_{\text{OUT, MAX}} + \frac{V_{\text{OUT}}(1\text{-}V_{\text{OUT}}/V_{\text{IN, MAX}})}{2 \times f_{\text{SW}} \times L}$

3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is desirable to choose an inductor with DCR<25m Ω to achieve a good overall efficiency.

Inductor vs. Output Capacitor

The instant PWM control strategy needs very little C_{OUT} to confirm stability. Too large inductor and C_{OUT} will lead to instability. The recommend inductance and output capacitor is shown as below.

Inductance vs. Output Capacitor Selection Table

	Cout						
L	10µF	22µF	80µF	120µF	350µF		
2.2µH	\checkmark	\checkmark	\checkmark				
4.7µH	\checkmark	\checkmark	\checkmark		×		
6.8µH		\checkmark		×	×		

OCP and SCP Protection Method

With load current increasing, as soon as the high side FET current gets higher than the peak current limit threshold, the high side FET will turn off and the low side FET will keep turning on until low side FET current decreases below the valley current limit threshold. If peak current limit is trigged twice, the valley current limit threshold will fold-back to 65%.

If the load current continues to increase, the output voltage will drop. When the output voltage falls below 1V, the output UVP will be detected and SY20109 will operate in hiccup mode. The hiccup frequency is 2kHz and the hiccup duty cycle is 50%. If the hard short is removed, the IC will return to normal operation.



SY20109

STB Pin Function

Two stage quiescent current can be selected via STB pin. If STB=1, the quiescent current will be 15μ A (typical). If STB=0, the quiescent current can be decreased to 400nA, while extra 3μ s delay time will be needed when SY20109 wakes up from the standby mode. As a side effect, the output undershot will be intensified if a dynamic load is attached to the output side in null load condition.

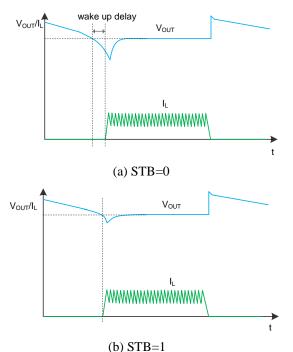


Figure 3. Load Transient Response

Bypass Mode

The SY20109 will enter 100% bypass mode when the input voltage is close to the output voltage. Once the input voltage falls below the bypass enter threshold V_{TH-} , the SY20109 will keep turning on the high side FET for 100% bypass mode. Because the output is connected to the input, the output voltage will track the input voltage minus the voltage drop across the internal high side FET and inductor, which is caused by the inductor current. Once the input voltage increases and trigger the bypass leave threshold V_{TH+} , the SY20109 will exit the 100% bypass mode and start switching again.

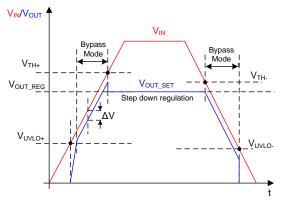


Figure 4. Bypass Mode Transition

The V_{TH+} , V_{TH-} , ΔV can be calculated as below: $V_{TH+}=V_{OUT_SET}\times 1.03\% + I_{OUT}\times (DCR_L+R_{DS(ON)1})$ $V_{TH-}=V_{OUT_SET}+I_{OUT}\times (DCR_L+R_{DS(ON)1})$ $\Delta V=I_{OUT}\times (DCR_L+R_{DS(ON)1})$

Layout Design

The layout design of the SY20109 is relatively simple. For the best efficiency and to minimize noise problems, we should place the following components close to the IC: C_{IN} , L, R_{H} and R_{L} .

- It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. If the board space allows, a ground plane will be highly desirable. Reasonable vias are suggested to be placed underneath the ground pad to enhance the soldering quality and thermal performance.
- 2) C_{IN} must be close to pins IN and GND. The loop area formed by C_{IN} and GND must be minimized.
- 3) The PCB copper area associated with LX pin must be minimized to avoid the potential noise problem.
- 4) The components R_H and R_L, and the trace connecting to the FB pin and OUT pin must NOT be adjacent to the LX net on the PCB layout to avoid the noise problem.



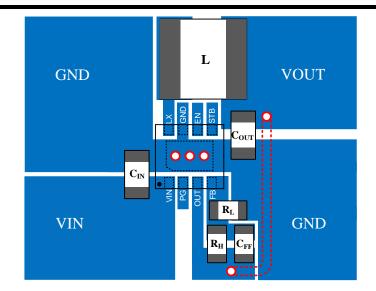
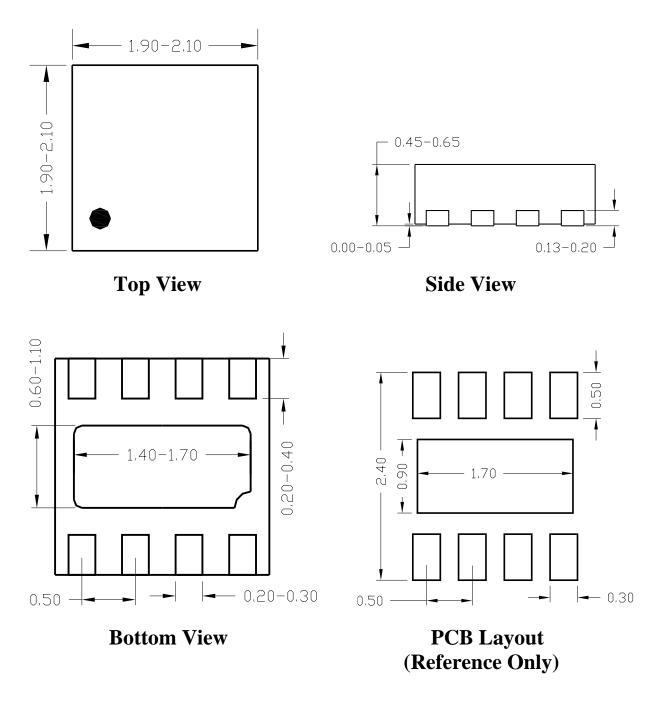


Figure 5. PCB Layout Suggestion





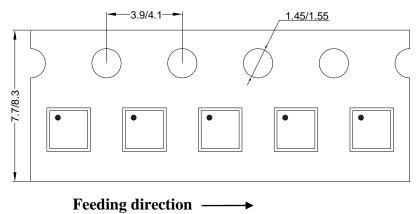


Notes: All dimension in millimeters. All dimensions don't include mold flash & metal burr.

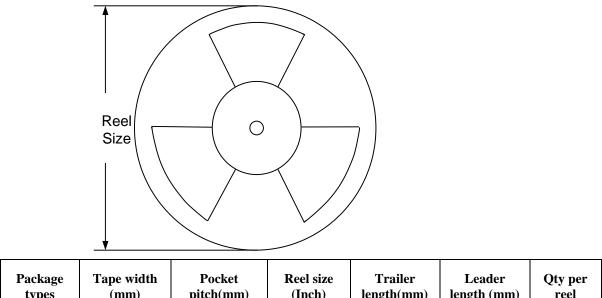




1. DFN2×2



2. Carrier Tape & Reel specification for packages



Package types	(mm)	pitch(mm)	(Inch)	length(mm)	Leader length (mm)	Qty per reel
DFN2×2	8	4	7''	400	160	3000

3. Others: NA



IMPORTANT NOTICE

1. **Right to make changes.** Silergy and its subsidiaries (hereafter Silergy) reserve the right to change any information published in this document, including but not limited to circuitry, specification and/or product design, manufacturing or descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products are sold subject to Silergy's standard terms and conditions of sale.

2. Applications. Application examples that are described herein for any of these products are for illustrative purposes only. Silergy makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Buyers are responsible for the design and operation of their applications and products using Silergy products. Silergy or its subsidiaries assume no liability for any application assistance or designs of customer products. It is customer's sole responsibility to determine whether the Silergy product is suitable and fit for the customer's applications and products planned. To minimize the risks associated with customer's products and applications, customer should provide adequate design and operating safeguards. Customer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Silergy assumes no liability related to any default, damage, costs or problem in the customer's applications or products, or the application or use by customer's third-party buyers. Customer will fully indemnify Silergy, its subsidiaries, and their representatives against any damages arising out of the use of any Silergy components in safety-critical applications. It is also buyers' sole responsibility to warrant and guarantee that any intellectual property rights of a third party are not infringed upon when integrating Silergy products into any application. Silergy assumes no responsibility for any said applications or for any use of any circuitry other than circuitry entirely embodied in a Silergy product.

3. Limited warranty and liability. Information furnished by Silergy in this document is believed to be accurate and reliable. However, Silergy makes no representation or warranty, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. In no event shall Silergy be liable for any indirect, incidental, punitive, special or consequential damages, including but not limited to lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges, whether or not such damages are based on tort or negligence, warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Silergy' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Standard Terms and Conditions of Sale of Silergy.

4. **Suitability for use.** Customer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of Silergy components in its applications, notwithstanding any applications-related information or support that may be provided by Silergy. Silergy products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Silergy product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Silergy assumes no liability for inclusion and/or use of Silergy products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

5. **Terms and conditions of commercial sale**. Silergy products are sold subject to the standard terms and conditions of commercial sale, as published at http://www.silergy.com/stdterms, unless otherwise agreed in a valid written individual agreement specifically agreed to in writing by an authorized officer of Silergy. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Silergy hereby expressly objects to and denies the application of any customer's general terms and conditions with regard to the purchase of Silergy products by the customer.

6. No offer to sell or license. Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights. Silergy makes no representation or warranty that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right. Information published by Silergy regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from Silergy under the patents or other intellectual property of Silergy.

For more information, please visit: www.silergy.com

© 2019 Silergy Corp.

All Rights Reserved.